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Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



Rev. 1 — 7 October 2010

**Product data sheet** 

## 1. Product profile

#### 1.1 General description

Quad PIN diode in a SOT753 package.

#### 1.2 Features and benefits

- 4 PIN diodes in a SOT753 package
- 300 kHz to 4 GHz
- High linearity
- Low insertion loss
- reduction in part count
- Low diode capacitance
- Low diode forward resistance

#### **1.3 Applications**

- RF attenuators
- Broadband system applications
- General purpose Voltage Controlled Attenuators for high linearity applications

## 2. Pinning information

| Pin | Description  | Simplified outline               | Graphic symbol  |
|-----|--------------|----------------------------------|-----------------|
| 1   | RF in        |                                  |                 |
| 2   | series bias  |                                  |                 |
| 3   | RF out       |                                  |                 |
| 4   | shunt 1 bias | <u>-</u> 1 <u>-</u> 2 <u>-</u> 3 |                 |
| 5   | shunt 2 bias |                                  | 1 2 3<br>sym143 |

## 3. Ordering information

#### Table 2. Ordering information

| Type number | Package |  |         |  |
|-------------|---------|--|---------|--|
|             | Name    | Description                              | Version |  |
| BAP64Q      | SC-74A  | plastic surface-mounted package; 5 leads | SOT753  |  |



## 4. Marking

| Table 3. Marking |              |
|------------------|--------------|
| Type number      | Marking code |
| BAP64Q           | A1           |

## 5. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter               | Conditions                |     | Min | Max  | Unit |
|------------------|-------------------------|---------------------------|-----|-----|------|------|
| V <sub>R</sub>   | reverse voltage         |                           | [1] | -   | 100  | V    |
| l <sub>F</sub>   | forward current         |                           | [1] | -   | 100  | mA   |
| P <sub>tot</sub> | total power dissipation | $T_{sp} = 90 \ ^{\circ}C$ | [1] | -   | 125  | mW   |
| T <sub>stg</sub> | storage temperature     |                           |     | -65 | +150 | °C   |
| Tj               | junction temperature    |                           |     | -65 | +150 | °C   |
|                  |                         |                           |     |     |      |      |

[1] single diode.

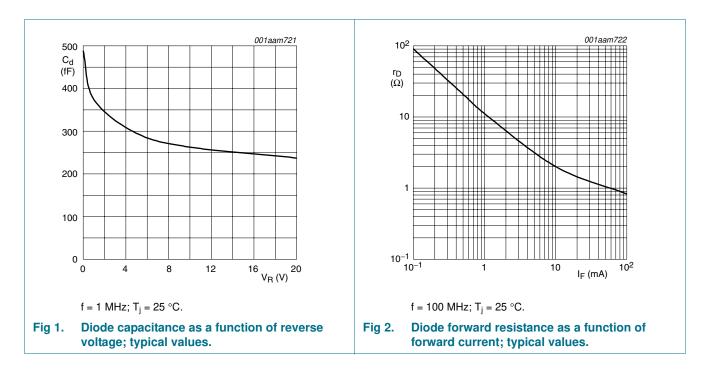
## 6. Thermal characteristics

| Table 5.              | Thermal characteristics                          |            |     |      |
|-----------------------|--|------------|-----|------|
| Symbol                | Parameter  | Conditions | Тур | Unit |
| R <sub>th(j-sp)</sub> | thermal resistance from junction to solder point |            | 350 | K/W  |

#### **Characteristics** 7.

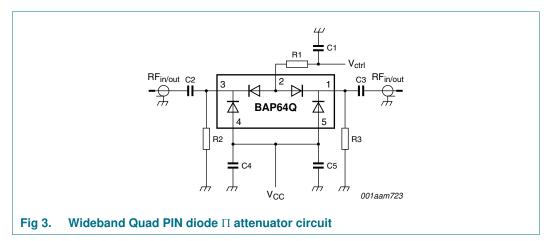
| Symbol                           | Parameter                | Conditions   |     | Min  | Тур  | Max  | Unit |
|----------------------------------|--------------------------|--|-----|------|------|------|------|
| Per diod                         | е                        |  |     |      |      |      |      |
| VF                               | forward voltage          | I <sub>F</sub> = 50 mA   |     | -    | 0.95 | 1.1  | V    |
| I <sub>R</sub>                   | reverse current          | V <sub>R</sub> = 20 V  |     | -    | -    | 1    | μA   |
|                                  |                          | V <sub>R</sub> = 100 V   |     | -    | -    | 10   | μA   |
| C <sub>d</sub> diode capacitance | f = 1 MHz; see Figure 1  |  |     |      |      |      |      |
|                                  |                          | $V_{R} = 0 V$  |     | -    | 0.52 | -    | pF   |
|                                  |                          | V <sub>R</sub> = 1 V   |     | -    | 0.37 | -    | pF   |
|                                  | V <sub>R</sub> = 20 V    |  | -   | 0.23 | 0.35 | pF   |      |
| r <sub>D</sub>                   | diode forward resistance | f = 100 MHz; see Figure 2  |     |      |      |      |      |
|                                  |                          | I <sub>F</sub> = 0.5 mA  | [1] | -    | 20   | 40   | Ω    |
|                                  |                          | I <sub>F</sub> = 1 mA  | [1] | -    | 10   | 20   | Ω    |
|                                  |                          | I <sub>F</sub> = 10 mA   | [1] | -    | 2    | 3.8  | Ω    |
|                                  |                          | I <sub>F</sub> = 100 mA  | [1] | -    | 0.7  | 1.35 | Ω    |
| τ∟                               | charge carrier life time | when switched from<br>$I_F = 10 \text{ mA to } I_R = 6 \text{ mA};$<br>$R_L = 100 \Omega;$<br>measured at $I_R = 3 \text{ mA}$ |     | -    | 1.55 | -    | μS   |

[1] Guaranteed on AQL basis: inspection level S4, AQL 1.0.



## 8. Application information

## 8.1 Application circuit



#### Table 7. List of components used for the typical application

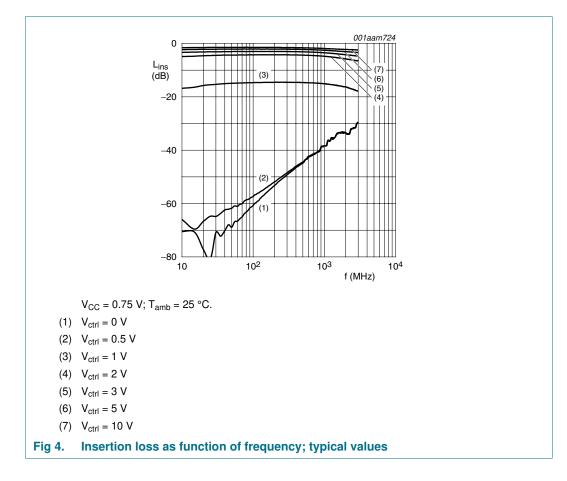
| Component          | Description    | Value  |
|--------------------|----------------|--------|
| C1, C2, C3, C4, C5 | chip capacitor | 10 nF  |
| R1, R2, R3         | chip resistor  | 1000 Ω |

#### 8.2 Quad PIN pi attenuator characteristics

#### Table 8. Typical performance for BAP64Q quad PIN diode $\Pi$ attenuator

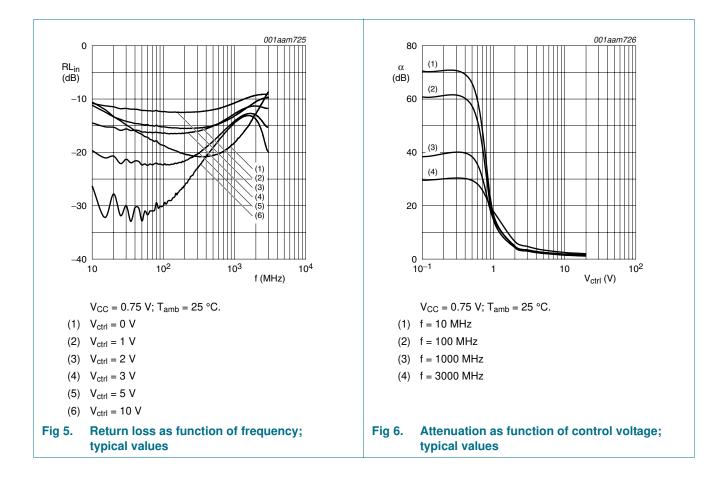
 $V_{CC} = 0.75 \text{ V}; T_{amb} = 25 \text{ °C}$  unless otherwise specified.

| Symbol           | Parameter                         | Test Conditions                     | Тур | Units |
|------------------|-----------------------------------|-------------------------------------|-----|-------|
| L <sub>ins</sub> | insertion loss                    | V <sub>ctrl</sub> = 10 V; f = 1 GHz | 1.8 | dB    |
| RL <sub>in</sub> | input return loss                 | V <sub>ctrl</sub> = 0 V; f = 1 GHz  | 18  | dB    |
| α                | attenuation                       | $V_{ctrl} = 0 V; f = 1 GHz$         | 38  | dB    |
| IP3 <sub>i</sub> | input third-order intercept point | f = 0.1 GHz                         |     |       |
|                  |                                   | $V_{ctrl} = 2 V$                    | 32  | dBm   |
|                  |                                   | $V_{ctrl} = 10 V$                   | 42  | dBm   |
|                  |                                   | f = 0.9 GHz                         |     |       |
|                  |                                   | $V_{ctrl} = 2 V$                    | 40  | dBm   |
|                  |                                   | $V_{ctrl} = 10 V$                   | 41  | dBm   |
|                  |                                   | f = 1.8 GHz                         |     |       |
|                  |                                   | V <sub>ctrl</sub> = 2 V             | 40  | dBm   |
|                  |                                   | V <sub>ctrl</sub> = 10 V            | 37  | dBm   |
|                  |                                   | f = 2.1 GHz                         |     |       |
|                  |                                   | V <sub>ctrl</sub> = 2 V             | 38  | dBm   |
|                  |                                   | V <sub>ctrl</sub> = 10 V            | 39  | dBm   |



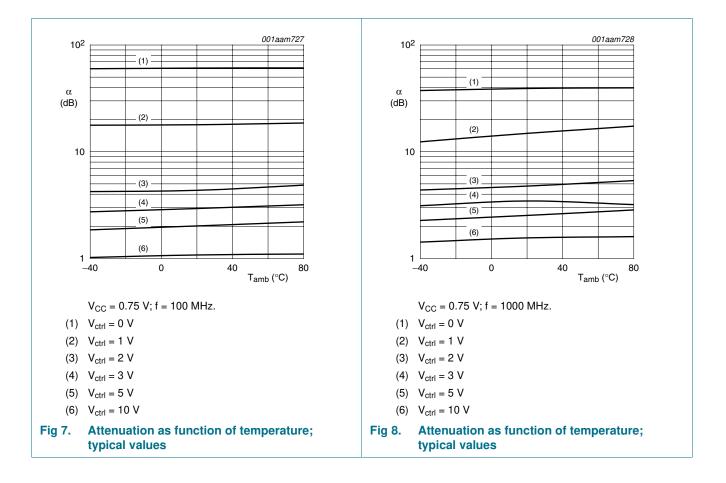
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## BAP64Q Quad PIN diode attenuator



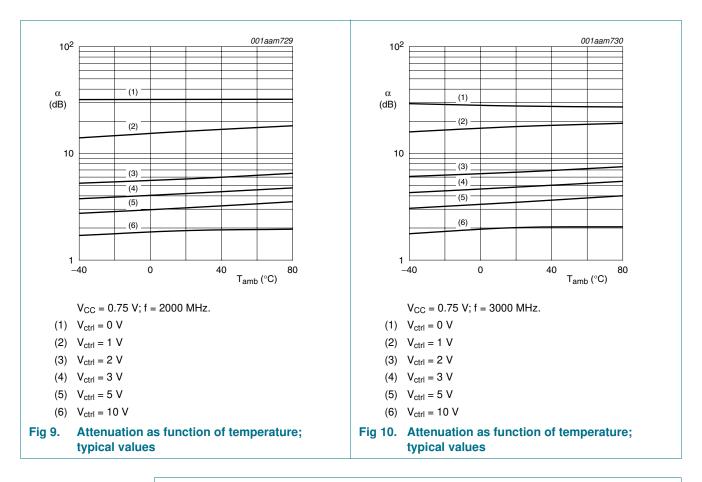
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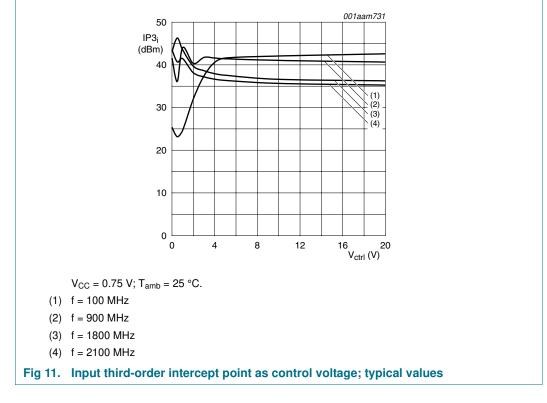
## BAP64Q Quad PIN diode attenuator



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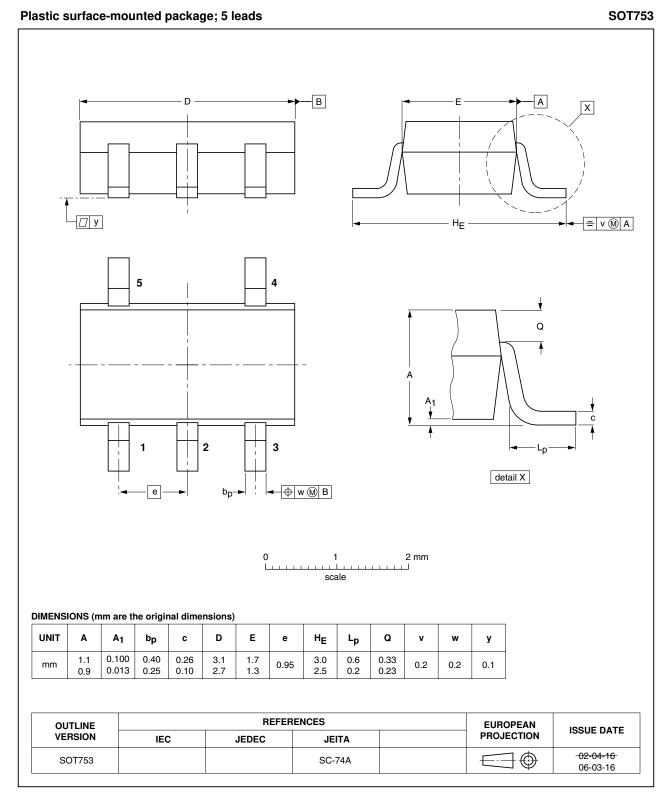
## BAP64Q Quad PIN diode attenuator





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## 9. Package outline



#### Fig 12. Package outline SOT753

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## **10. Abbreviations**

| Table 9. Ab | breviations                |
|-------------|----------------------------|
| Acronym     | Description                |
| AQL         | Acceptable Quality Level   |
| PIN         | P-type, Intrinsic, N-type  |
| RF          | Radio Frequency            |
| S4          | Special inspection level 4 |

## **11. Revision history**

#### Table 10.Revision history

| Document ID | Release date | Data sheet status  | Change notice | Supersedes |
|-------------|--------------|--------------------|---------------|------------|
| BAP64Q v.1  | 20101007     | Product data sheet | -             | -          |

## 12. Legal information

#### 12.1 Data sheet status

| Document status[1][2]          | Product status <sup>[3]</sup> | Definition  |
|--------------------------------|-------------------------------|---|
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[2] The term 'short data sheet' is explained in section "Definitions".

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#### **Quad PIN diode attenuator**

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## **BAP64Q**

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